



STGW30NC120HD Alternative

N-CHANNEL 1200V Trench and Fieldstop IGBT



Part Number: JAD112MI40

PRODUCT SUMMARY		
V_{CE} (V)	1200	
I_C (A)	80 (TC=25°C)	40 (TC=100°C)
$V_{CE(sat)}$ (V)	1.8	
I_{CM} (A)	120	

FEATURES

- Very Low V_{CEsat}
- Low turn-off losses
- High speed switching
- Maximum junction temperature 175°C
- Ultra low gate charge (Q_g)
- Avalanche energy rated (UIS)

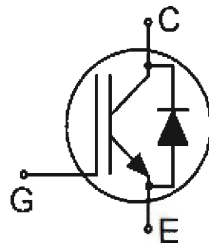


RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Telecommunications
 - Server and telecom power supplies
- Lighting
 - High-intensity discharge (HID)
 - Fluorescent ballast lighting
- Consumer and computing
 - ATX power supplies
- Industrial
 - Welding
 - Battery chargers
- Renewable energy
 - Solar (PV inverters)
- Switch mode power supplies (SMPS)

TO-247



Package pin definition

- Pin1 G - Gate
- Pin2 C & backside - Collector
- Pin3 E - Emitter

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Collector-Emitter Voltage	V_{CE}	1200	V
Gate-Emitter Voltage	V_{GE}	± 30	
Continuous Collector Current ($T_J = 150^\circ\text{C}$)	V_{GE} at 15 V	$T_C = 25^\circ\text{C}$	A
		$T_C = 100^\circ\text{C}$	
Pulsed Collector Current ^a	I_{CM}	120	
Diode Forward Current ^b	I_F	40	A
Maximum Power Dissipation		$T_C = 25^\circ\text{C}$	W
		$T_C = 100^\circ\text{C}$	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +175	°C
Short Circuit Withstand Time $T_C=150^\circ\text{C}$	$V_{GE} = 15\text{V}, V_{CE} \leq 400\text{V}$		μs
Short Circuit Withstand Time $T_C=100^\circ\text{C}$			
Soldering Recommendations (Peak Temperature) ^c	for 10 s	260	°C

Notes

- Repetitive rating; pulse width limited by maximum junction temperature.
- Current limited by maximum junction temperature.
- 1.6 mm from case.



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THERMAL RESISTANCE RATINGS				
PARAMETER	SYMBOL	TYP.	MAX.	UNIT
Maximum Junction-to-Ambient	R_{thJA}	-	40	°C/W
Maximum Junction-to-Case	R_{thJC}	-	0.5	

SPECIFICATIONS ($T_J = 25\text{ °C}$, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Collector-Emitter Breakdown Voltage	BV_{CE}	$V_{GE} = 0\text{ V}, I_C = 250\text{ }\mu\text{A}$ $V_{GE} = 0\text{ V}, I_C = 1\text{ mA}$		1200 1200	- -	- -	V
Gate-Source Threshold Voltage (N)	$V_{GE(th)}$	$V_{CE} = V_{GE}, I_D = 250\text{ }\mu\text{A}$		4	5	6	V
Zero Gate Voltage Collector Current	I_{CES}	$V_{CE} = 1200\text{ V}, V_{GE} = 0\text{ V}, T_J = 25\text{ °C}$		-	1	20	μA
		$V_{CE} = 1200\text{ V}, V_{GE} = 0\text{ V}, T_J = 150\text{ °C}$		-	1000	-	μA
Gate-Emitter Leakage Current	I_{GES}	$V_{CE} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$		-	-	100	nA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE} = 15\text{ V}$	$I_C = 40\text{ A}$	-	1.7	2.1	V
Forward Transconductance	g_{fs}	$V_{CE} = 20\text{ V}, I_C = 40\text{ A}$		-	40	-	S
Dynamic							
Input Capacitance	C_{ies}	$V_{GE} = 0\text{ V}, V_{CE} = 25\text{ V},$ $f = 500\text{ KHz}$		-	4300	-	pF
Output Capacitance	C_{oes}			-	230	-	
Reverse Transfer Capacitance	C_{res}			-	68	-	
Turn-on Energy	E_{on}	$V_{CE} = 400\text{ V}, V_{GE} = 0/15\text{V},$ $I_C = 40\text{ A}, R_g = 10\Omega$		-	0.4	-	nJ
Turn-off Energy	E_{off}			-	0.5	-	
Total Gate Charge	Q_g	$V_{GE} = 15\text{ V}$	$I_C = 40\text{ A}, V_{CE} = 400\text{ V}$	-	178	-	nC
Gate-Emitter Charge	Q_{ge}			-	16	-	
Gate to Collector Charge	Q_{gc}			-	42	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{CE} = 400\text{ V}, V_{GE} = 0/15\text{V},$ $I_C = 40\text{ A}, R_g = 10\Omega$		-	68	-	ns
Rise Time	t_r			-	52	-	
Turn-Off Delay Time	$t_{d(off)}$			-	178	-	
Fall Time	t_f			-	32	-	
Internal emitter inductance measured 5 mm	L_E			-	13	-	nH
Diode Characteristics							
Diode Forward Current	I_F	IGBT symbol showing the integral reverse junction diode		-	-	40	A
Pulsed Diode Forward Current	I_{FM}			-	-	120	
Diode Forward Voltage	V_F	$I_F = 40\text{ A}$		-	1.73	2.0	V
Reverse Recovery Time	t_{rr}	$T_J = 25\text{ °C}, I_F = 40\text{ A},$ $dI_F/dt = 200\text{ A}/\mu\text{s}, V_R = 400\text{ V}$		-	82	-	ns
Reverse Recovery Charge	Q_{rr}			-	0.24	-	μC
Reverse Recovery Current	I_{RRM}			-	14	-	A



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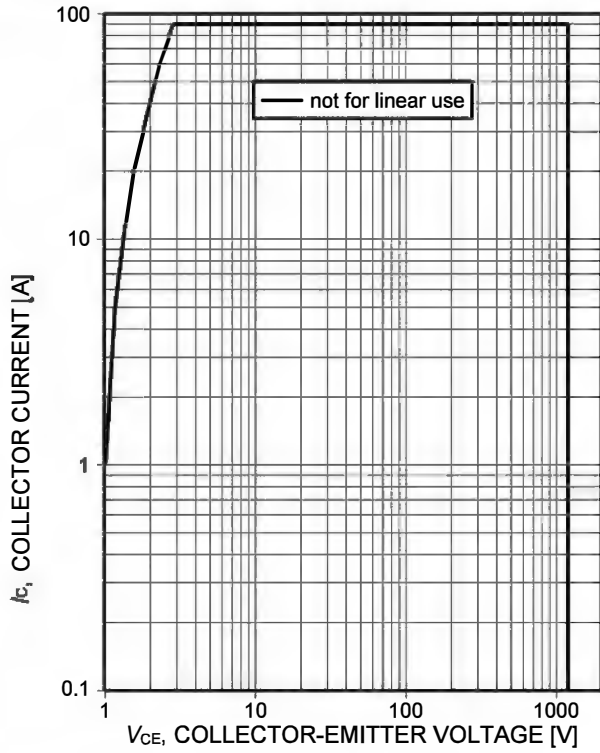


Figure 1. Forward bias safe operating area

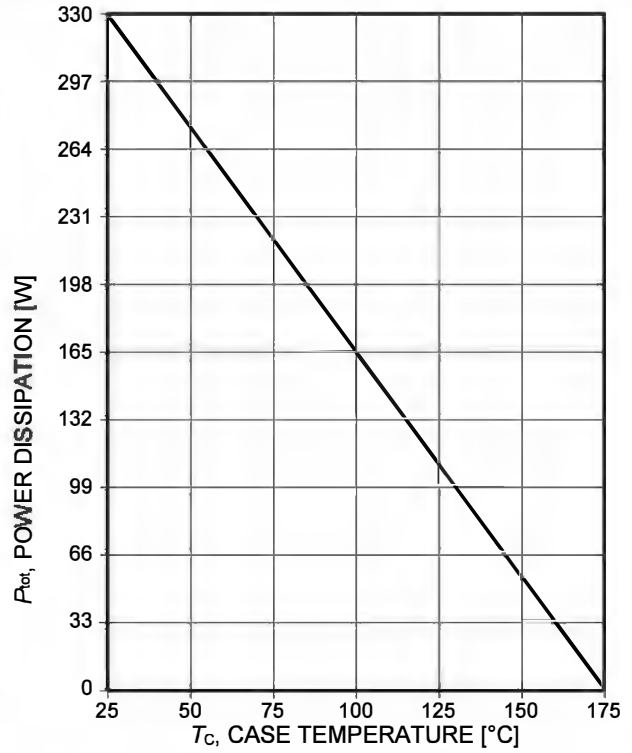


Figure 2. Power dissipation as a function of case temperature

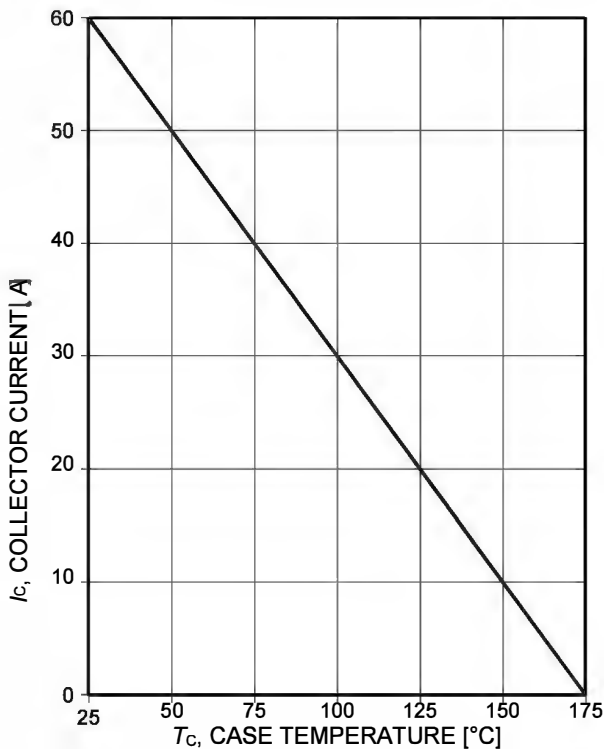


Figure 3. Collector current as a function of case temperature

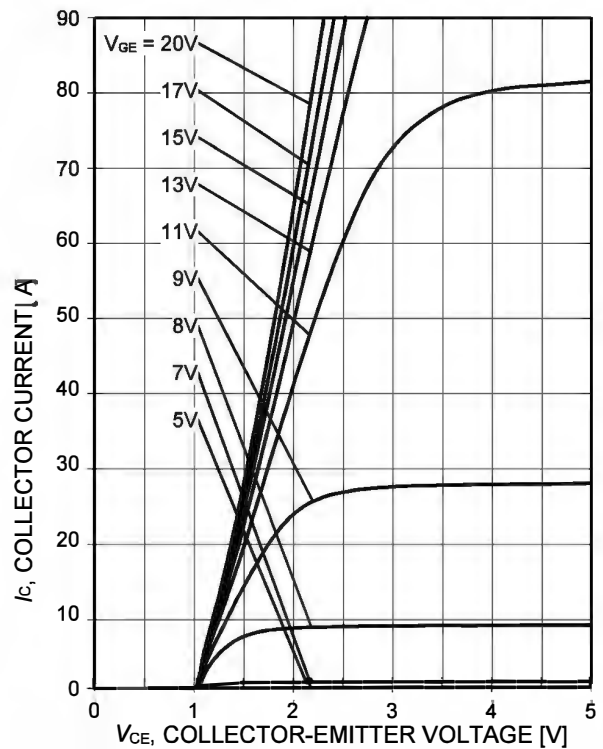


Figure 4. Typical output characteristic

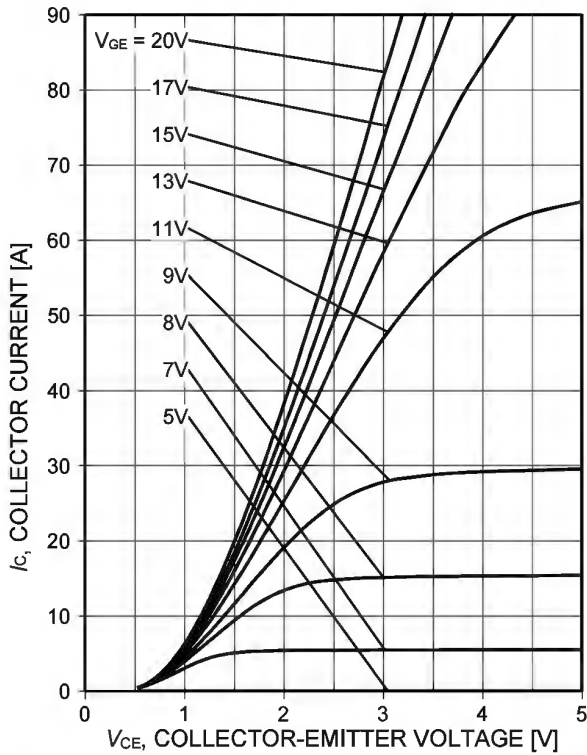


Figure 5. Typical output characteristic

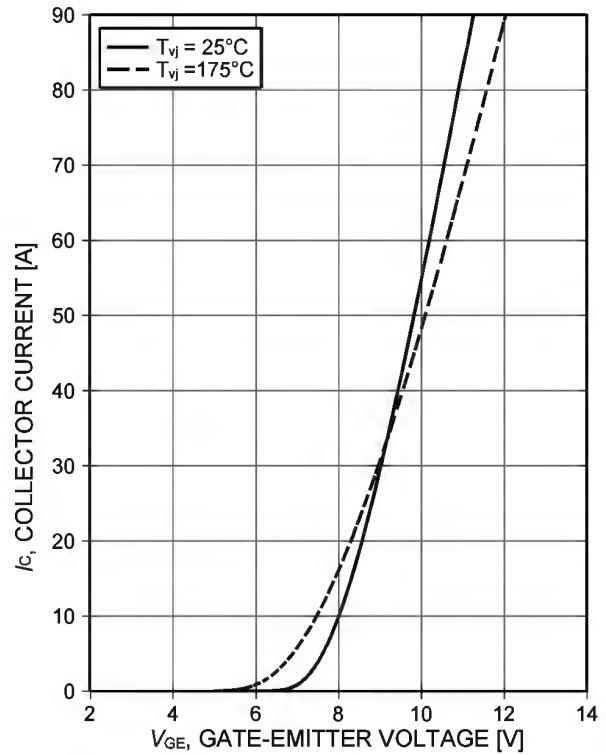


Figure 6. Typical transfer characteristic

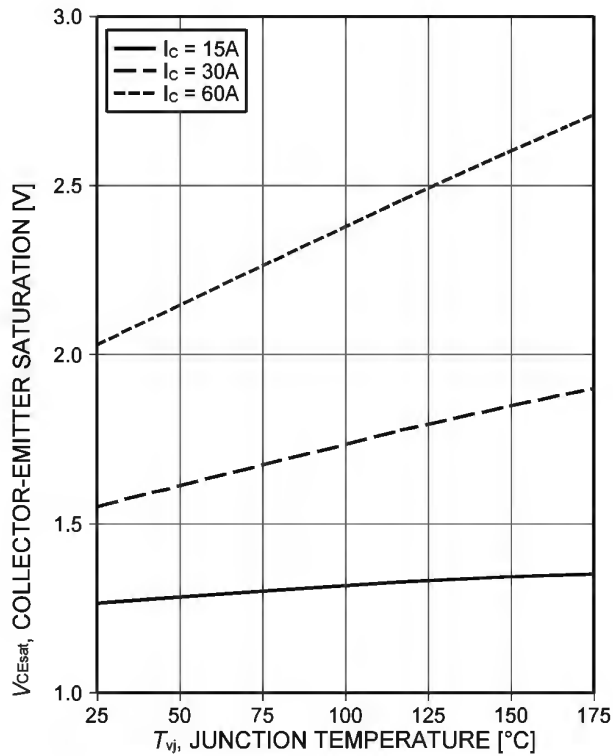


Figure 7. Typical collector-emitter saturation voltage as a function of junction temperature

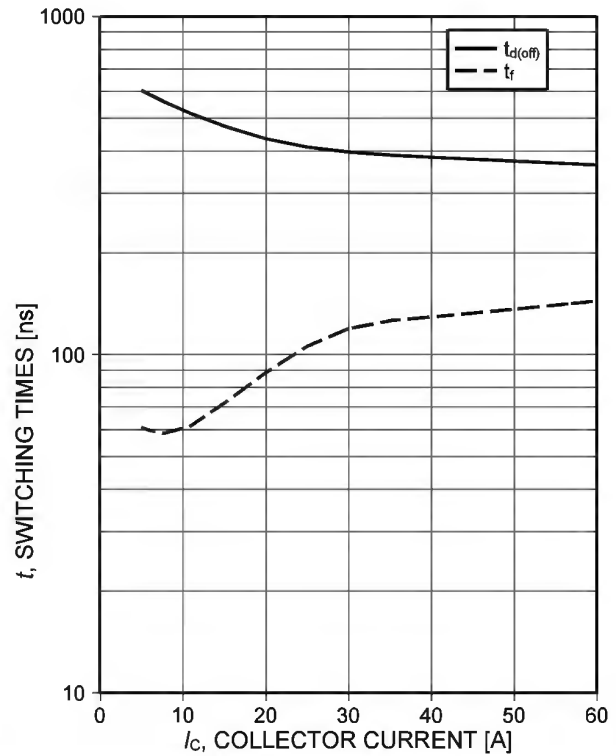


Figure 8. Typical switching times as a function of collector current

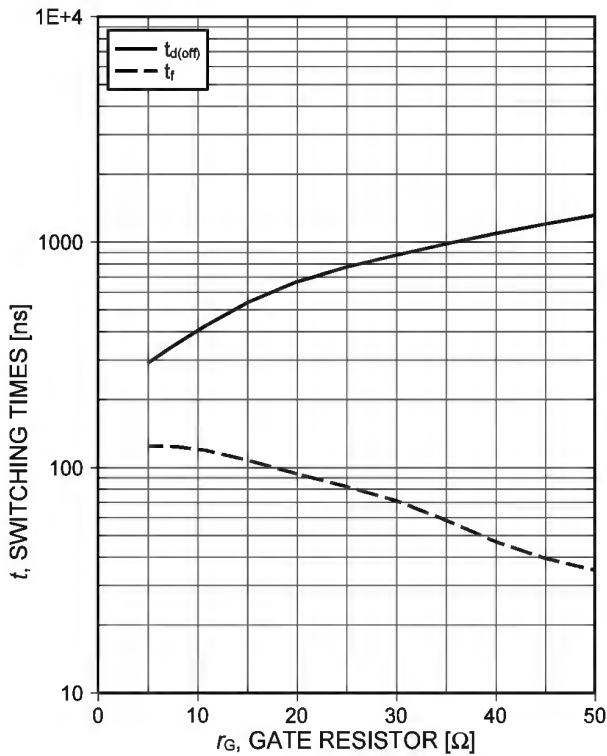


Figure 9. Typical switching times as a function of gate resistor

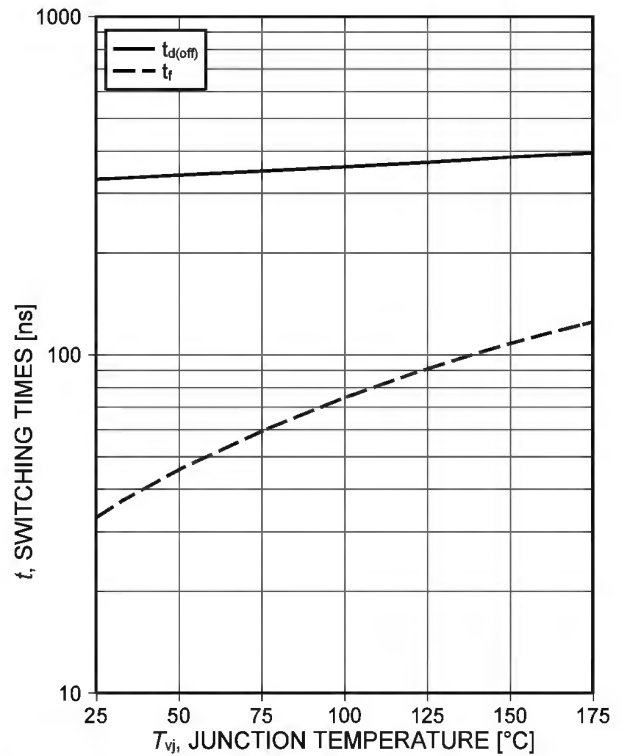


Figure 10. Typical switching times as a function of junction temperature

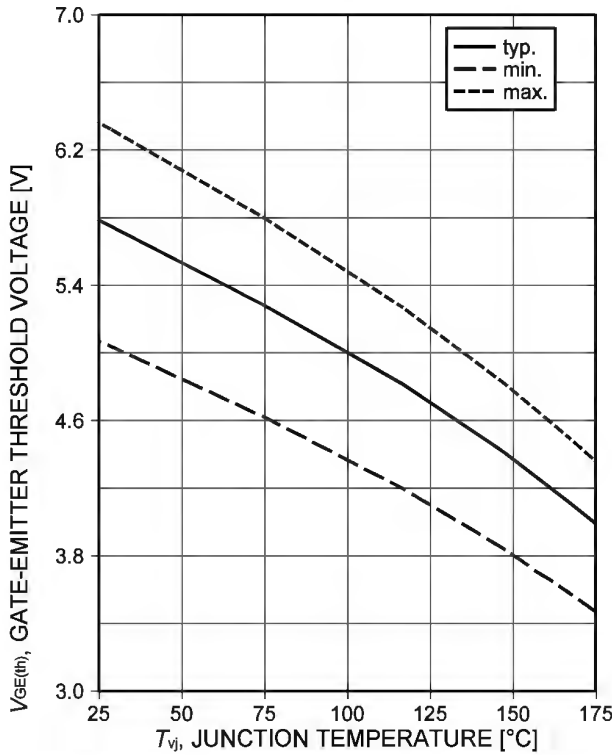


Figure 11. Gate-emitter threshold voltage as a function of junction temperature

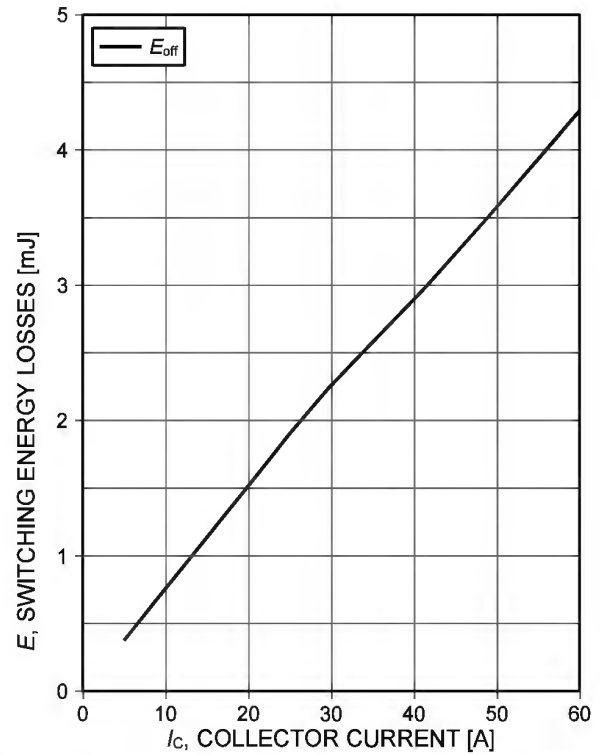


Figure 12. Typical switching energy losses as a function of collector current

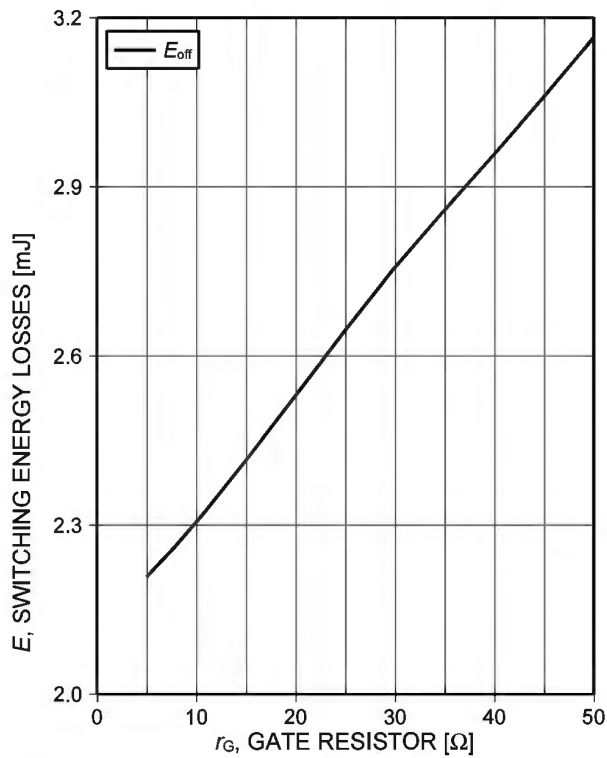


Figure 13. Typical switching energy losses as a function of gate resistor

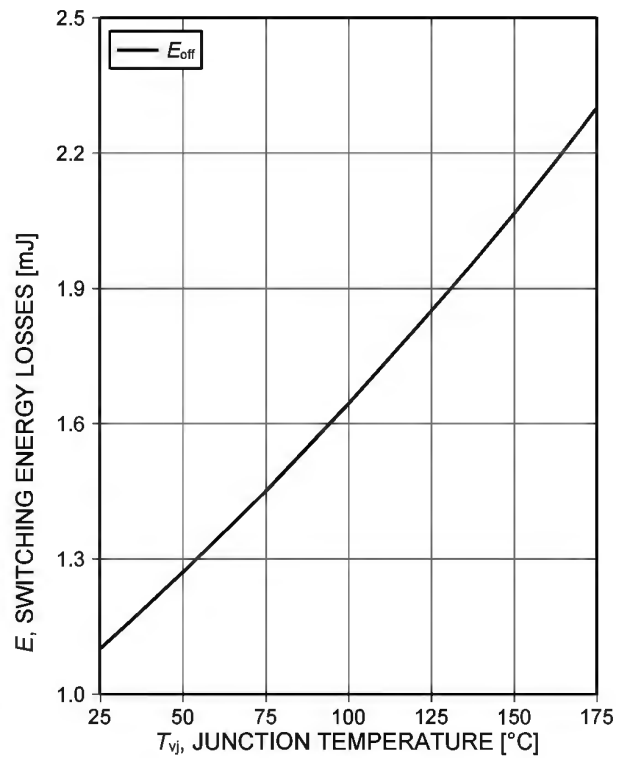


Figure 14. Typical switching energy losses as a function of junction temperature

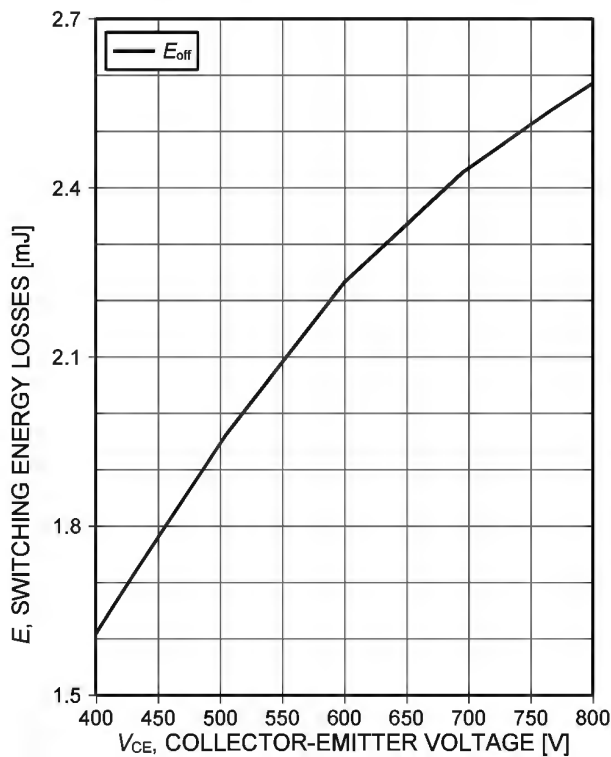


Figure 15. Typical switching energy losses as a function of collector emitter voltage

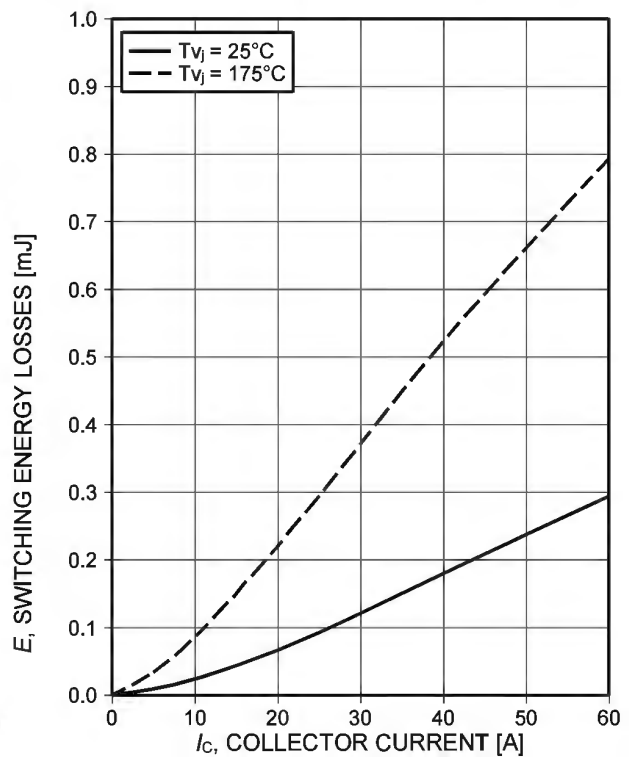


Figure 16. Typical turn off switching energy loss for soft switching

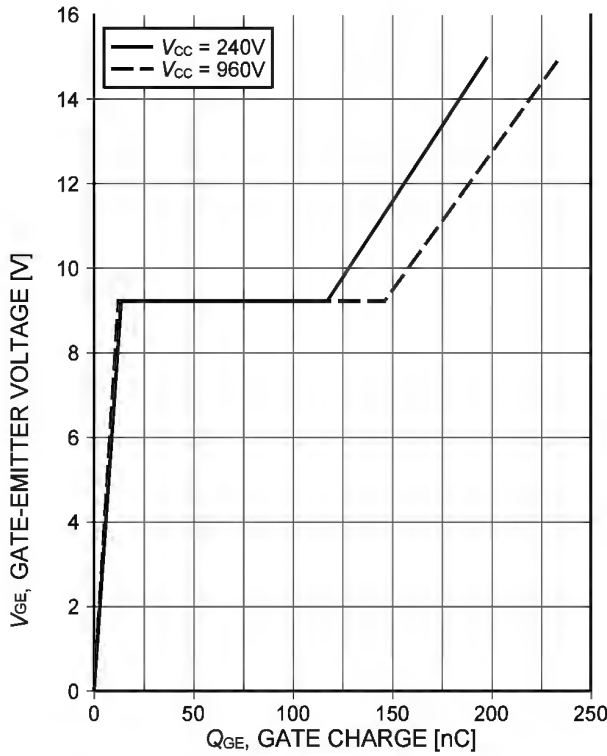


Figure 17. Typical gate charge

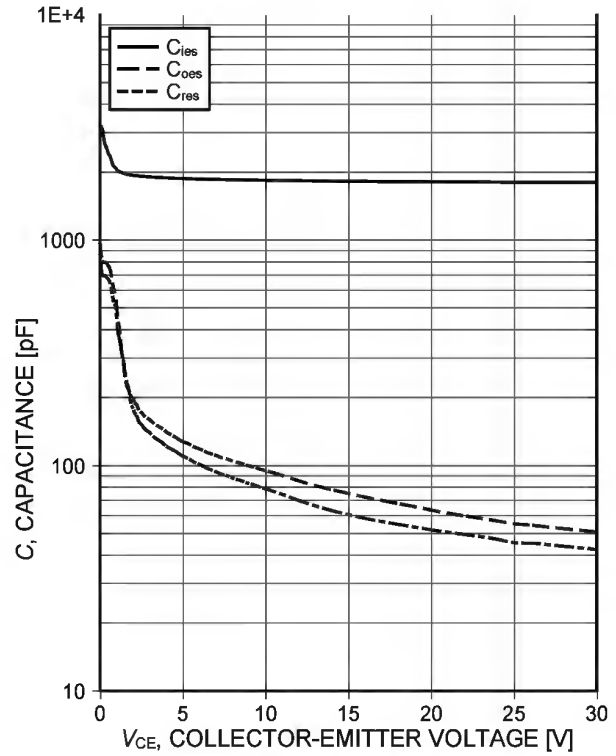


Figure 18. Typical capacitance as a function of collector-emitter voltage

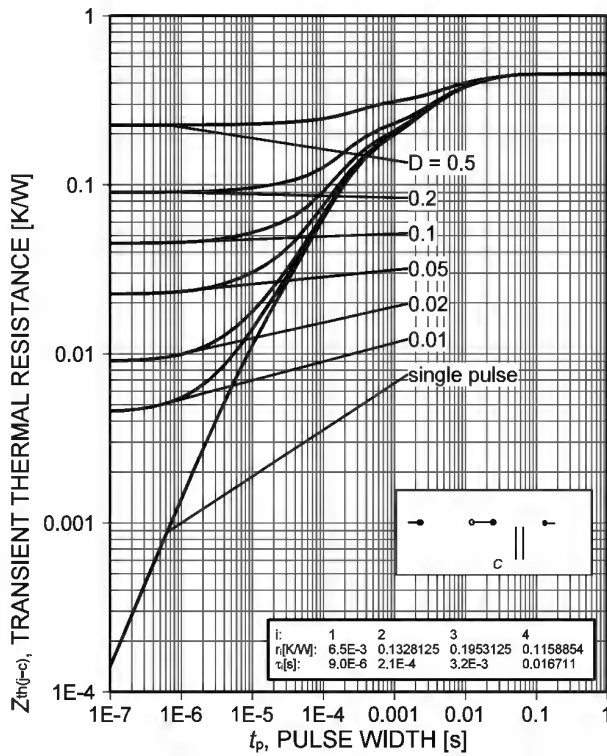


Figure 19. IGBT transient thermal resistance

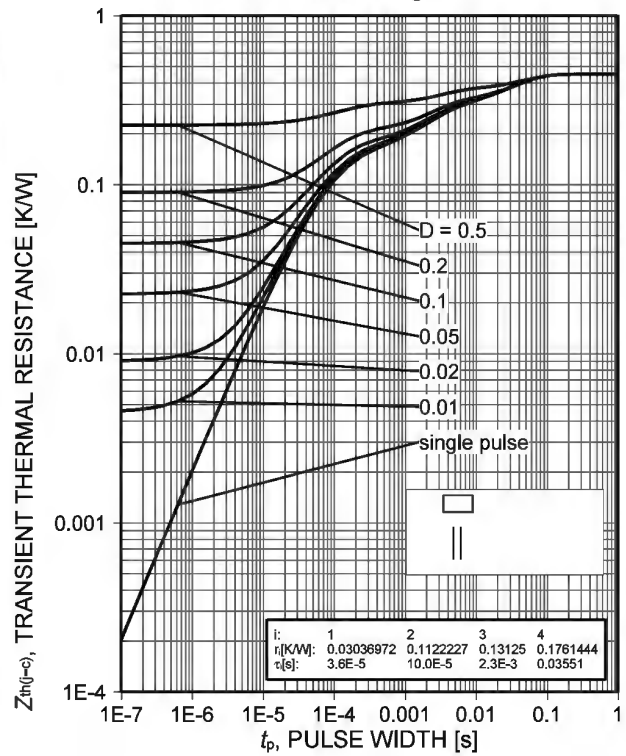


Figure 20. Diode transient thermal impedance as a function of pulse width



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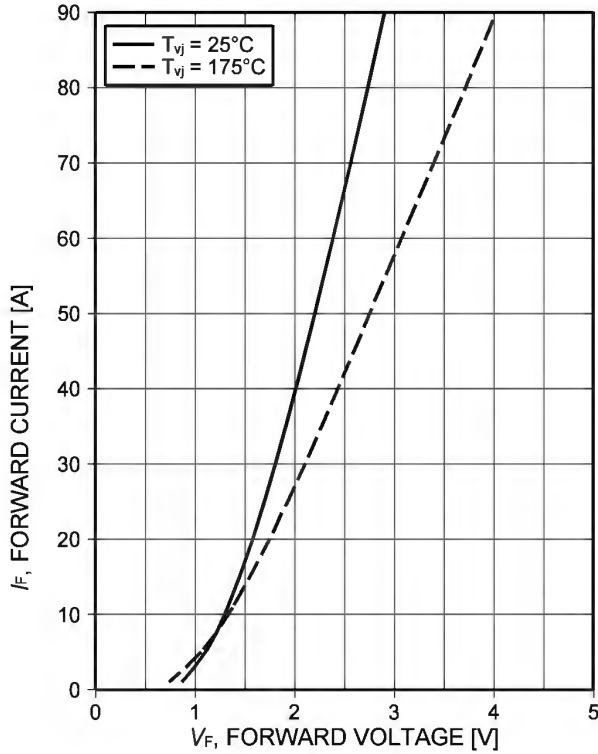


Figure 21. Typical diode forward current as a function of forward voltage

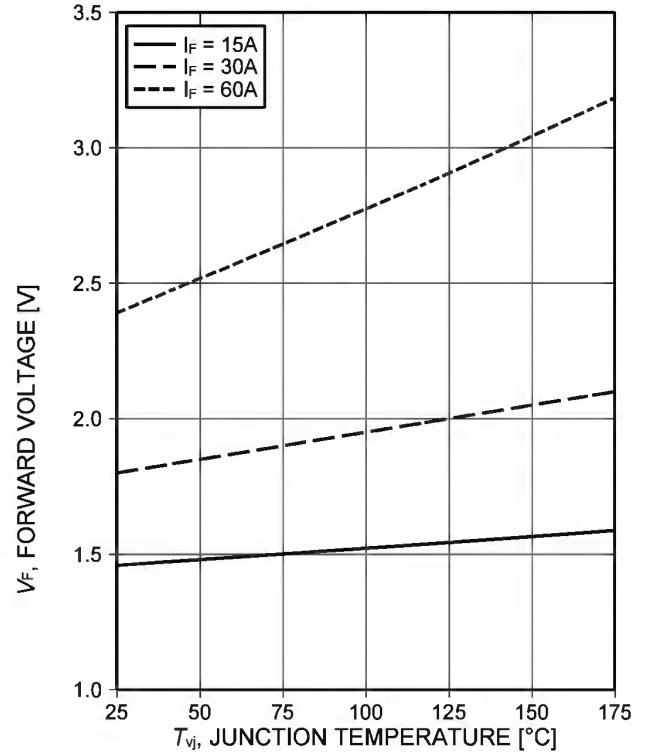


Figure 22. Typical diode forward voltage as a function of junction temperature

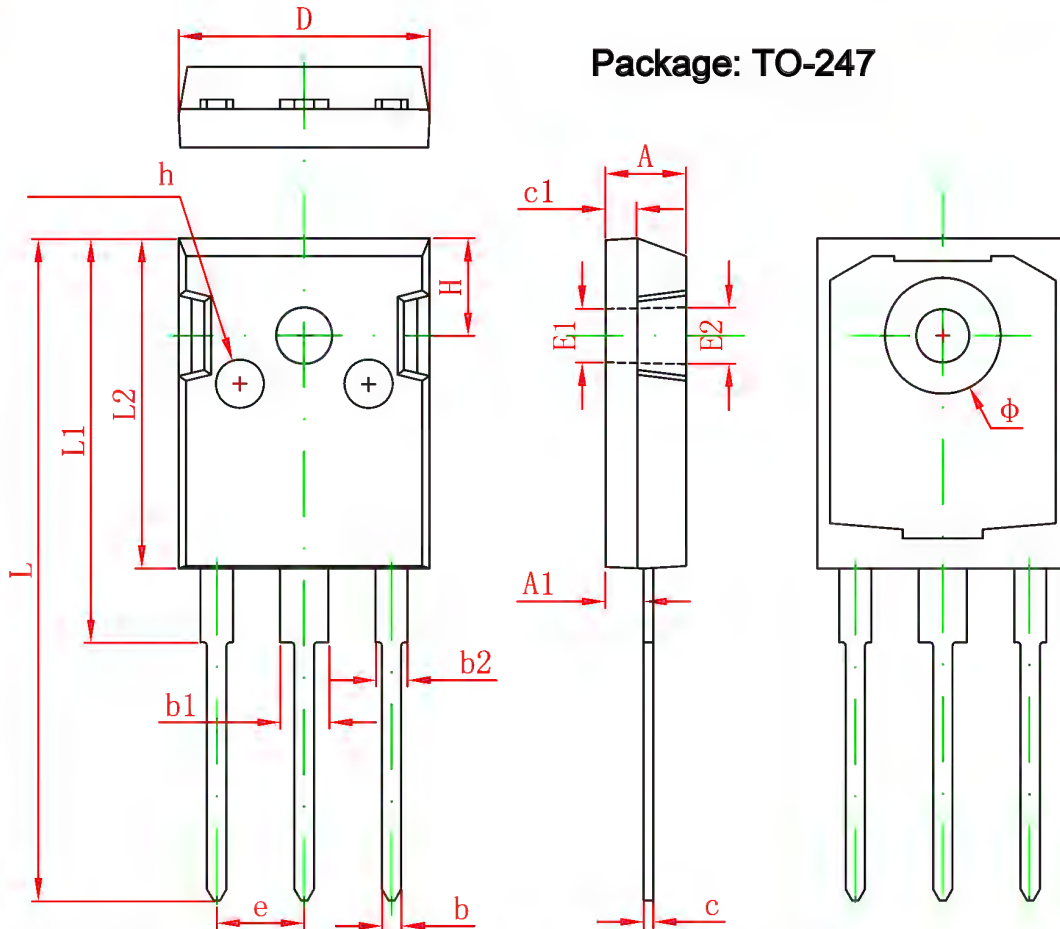


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Package: TO-247



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 REF		0.138 REF	
E2	3.600 REF		0.142 REF	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
φ	7.100	7.300	0.280	0.287
e	5.450 TYP		0.215 TYP	
H	5.980 REF		0.235 REF	
h	0.000	0.300	0.000	0.012

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